2SC4003



# **High-Voltage Driver Applications**

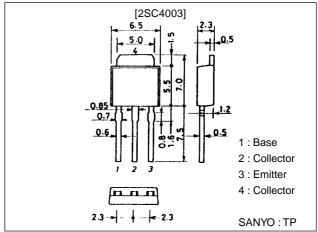
#### **Features**

- $\cdot$  High breakdown voltage.
- · Adoption of MBIT process.
- · Excellent hFE linearity.

## **Package Dimensions**

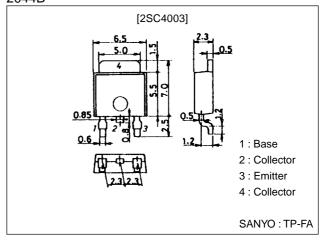
unit:mm

2045B



unit:mm

### 2044B



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# **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

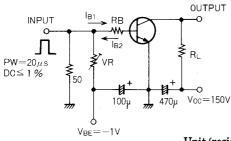
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		400	V
Collector-to-Emitter Voltage	VCEO		400	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		5	V
Collector Current	lc		200	mA
Collector Current (Pulse)	I <sub>CP</sub>		400	mA
Collector Dissipation	PC		1	W
		Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =300V, I <sub>E</sub> =0			0.1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0			0.1	μA
DC Current Gain	hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =50mA	60*		200*	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =30V, I <sub>C</sub> =10mA		70		MHz
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =50mA, I <sub>B</sub> =5mA			0.6	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =50mA, I <sub>B</sub> =5mA			1.0	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =10μA, I <sub>E</sub> =0	400			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	400			V
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =10μA, I <sub>C</sub> =0	5			V
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =30V, f=1MHz		4		pF
Reverse Transfer Capacitance	C <sub>re</sub>	V <sub>CB</sub> =30V, f=1MHz		3		pF
Turn-ON Time	ton	See specified test circuit.		0.25		μs
Turn-OFF Time	toff	See specified test circuit.		5.0		μs

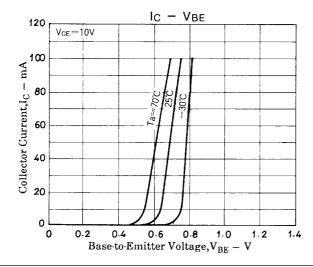
60 D 120 100 E 200

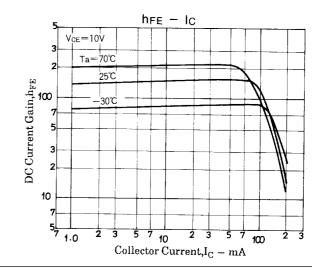
### **Switching Time Test Circuit**

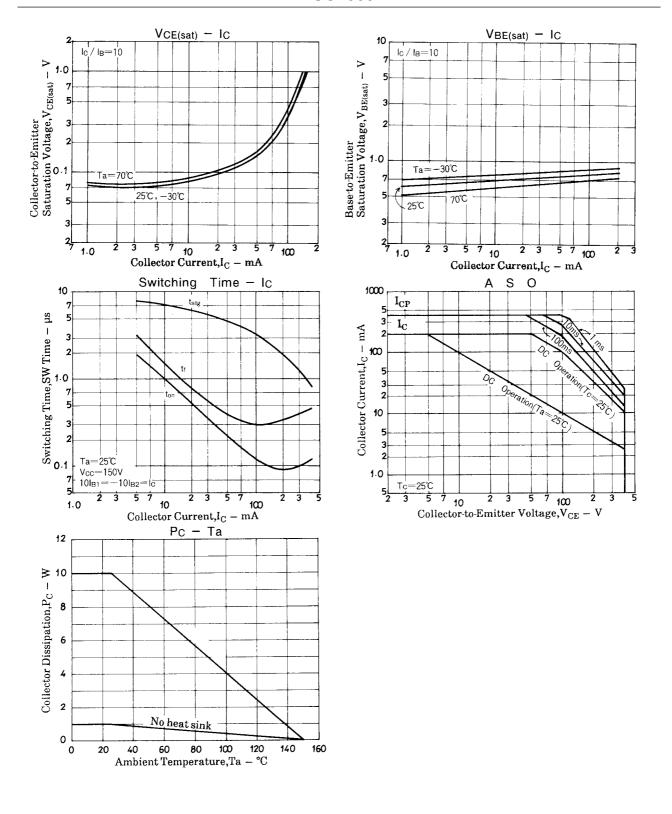


Unit (resistance :  $\Omega$ , capacitance : F)

$$\begin{array}{l} \text{10I}_{\text{B1}}\!=\!-\text{10I}_{\text{B2}}\!=\!\text{I}_{\text{C}}\!=\!50\text{mA} \\ R_{\text{L}}\!=\!3\text{k}\Omega, R_{\text{B}}\!=\!200\Omega \text{ at I}_{\text{C}}\!=\!50\text{mA} \end{array}$$







#### 2SC4003

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